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1. Pin Group Information

1.1 Device package information

The V850ES/Fx3-L device series comprises several members. An overview with the pin and package information is given in the following table:

Series Member	# Pins	Device package information
µPD70F3610 µPD70F3611 µPD70F3612 µPD70F3613 µPD70F3614	64	FE3-L
µPD70F3615 µPD70F3616 µPD70F3617 µPD70F3618 µPD70F3619	80	FF3-L
µPD70F3620 µPD70F3621 µPD70F3622	100	FG3-L

This document describes the specification for the V850ES/FF3-L.

1.2 Pin Groups 1x: Pins supplied by EVDD

1B: (SHMT1)
- P04, P30-31, P34; P40, P91, P913-915 (FE3-L)
- P04, P30-31, P34; P38-39, P40, P91, P913-915 (FF3-L)
- P04, P30-31, P34; P36-39, P40, P91, P911, P913-915 (FG3-L)

1D: (SHMT3)
- P00-03, P05-P06, P32-33, P35, P41-42, P50-55, P90, P96-99 (FE3-L)
- P00-03, P05-P06, P32-33, P35, P41-42, P50-55, P90, P96-99 (FF3-L)
- P00-03, P05-P06, P10-11, P32-33, P35, P41-42, P50-55, P90, P92-910, P912 (FG3-L)

1.3 Pin Groups 2x: Pins supplied by EVDD

2A: (CMOS)
- PCM0-1 (FE3-L)
- PCM0-3, PCS0-1, PCT0-1, PCT4, PCT6 (FF3-L)

2D: (SHMT3)
- PDL0-7 (FE3-L)
- PDL0-11 (FF3-L)

1.4 Pin Groups 3x: Pins supplied by BVDD

3A: (CMOS)
- PCM0-3, PCS0-1, PCT0-1, PCT4, PCT6 (FG3-L)

3D: (SHMT3)
- PDL0-13 (FG3-L)

1.5 Pin Groups 4: Pins supplied by AVREF0

4: (CMOS)
- P70-79 (FE3-L)
- P70-711 (FF3-L)
- P70-715 (FG3-L)

1.6 Pin Groups 6: Pins supplied by EVDD

- RESET (SHMT2)
- IC, FLMD0

1.7 Pin Groups 7: Pins supplied by VRO

- X1, X2, XT1, XT2

2.2 Capacities

(Ta = 25°C, VDD = EVDD = AVREF0 = VSS = EVSS = AVSS = 0V)

Parameter	**Symbol**	Conditions	MIN.	TYP.	MAX.	Unit
Input/output capacitance	CIO	f=1MHz, Not measured pins is 0V.			10	pF

2.3 Operating condition

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, C=4.7uF, VDD = EVDD = 3.3 to 5.5V, AVREF0 = 3.3 to 5.5V, VSS = EVSS = AVSS = 0V)

Internal System clock frequency (f_{VBCLK})	Supply voltage	Operating Condition
$4.0 \le f_{xx} \le 20$MHz Note1	3.5V≤VDD≤5.5V Note1	Operation of functions is enabled
	3.3V≤VDD<3.5V	The following functions are operable: • CPU • Flash (including programming • RAM • IO Buffer • Port • WT • WDT • INT • CLM • POC • LVI
	3.3V≤AVRF0≤5.5V	• A/D Converter • stop ADC for AVREF0 < 4.0V (ADA0CE bit =0) • Refer to chapter '2.8 A/D Converter' for details.
32kHz≤f_{XT}≤35kHz (Crystal)	3.3V≤VDD<5.5V Note1	-
12.5kHz≤f_{XT}≤27.5kHz Note2 (RC)		
f_{RL} (240kHz Internal-OSC)	3.3V≤VDD<5.5V Note1	-

Notes: 1. VDD = EVDD

2. RC Oscillation frequency is min. 25kHz max. 55kHz. This clock is divided by 2 internally.

2.5.2 Sub System Clock Oscillation Circuit Characteristics

(Ta = -40 to +85°C, C=4.7uF, VDD = EVDD = 3.3 to 5.5V, AVREF0 = 3.3 to 5.5V, VSS = EVSS = AVSS = 0V)

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Crystal resonator	Refer to Figure 1	Oscillator frequency (fxt)Note1		32	32.768	35	kHz
		Oscillation stabilization time Note2				10	s

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, C=4.7uF, VDD = EVDD = 3.3 to 5.5V, AVREF0 = 3.3 to 5.5V, VSS = EVSS = AVSS = 0V)

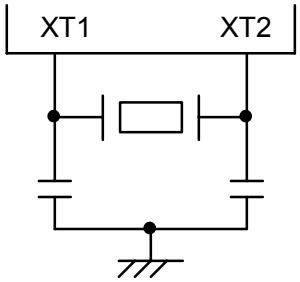
Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
RC resonator	Refer to Figure 2	Oscillator frequencyNote1,4	R=390KΩ ±5% Note3, C=47pF±10% Note3	25	40	55	kHz
		Oscillation stabilization time Note2				100	µs

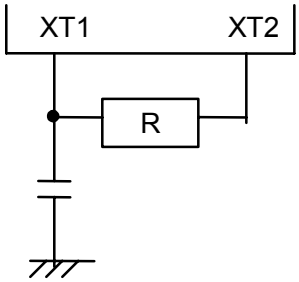
Notes: 1. Indicates only oscillation circuit characteristics. Refer to "AC Characteristic" for cpu operation clock.

2. Time required to stabilize oscillation after VDD reaches oscillator voltage range min. 3.3V

3. In order to avoid the influence of wiring capacity, shorten wiring as much as possible.

4. RC Oscillation frequency is typ. 40kHz. This clock is divided (1/2) internally. In case of RC Oscillator, internal system clock frequency (fxt) is min. 12.5kHz, typ. 20kHz, max. 27.5kHz.





2.5.3 Internal-OSC Characteristics

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, C=4.7uF, VDD = EVDD = 3.3 to 5.5V, AVREF0 = 3.3 to 5.5V, VSS = EVSS = AVSS = 0V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output frequency	f_{RL}	240kHz Internal-OSC	204	240	276	kHz
	f_{RH}	8MHz Internal-OSC	7.2	8.0	8.8	MHz
Oscillation stabilization time		240kHz Internal-OSC		10	36	µs
		8MHz Internal-OSC	51	92	256	µs

2.6 DC Characteristics

2.6.1 Input/Output Level

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, C=4.7uF, VDD = EVDD = 3.3 to 5.5V, AVREF0 = 3.3 to 5.5V, VSS = EVSS = AVSS = 0V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
High level input voltage	VIH1	Pin Group 1B		0.7·EVDD		EVDD	V
	VIH2	Pin Group 1D		0.8·EVDD		EVDD	V
		Pin Group 2D		0.8·EVDD		EVDD	V
	VIH3	Pin Group 2A		0.7·EVDD		EVDD	V
	VIH4	Pin Group 4		0.7·AVREF0		AVREF0	V
	VIH5	Pin Group 6		0.8·EVDD		EVDD	V
Low level input voltage	VIL1	Pin Group 1B		EVSS		0.3·EVDD	V
	VIL2	Pin Group 1D		EVSS		0.4·EVDD	V
		Pin Group 2D		EVSS		0.4·EVDD	V
	VIL3	Pin Group 2A		EVSS		0.3·EVDD	V
	VIL4	Pin Group 4		AVSS		0.3·AVREF0	V
	VIL5	Pin Group 6		EVSS		0.2·EVDD	V
Input hysteresis	VHYS1	Pin Group 1B	Center point at 0.5·EVDD Note3		0.267·EVDD - 0.51V		V
	VHYS2	Pin Group 1D	Center point at 0.6·EVDD Note3		0.192·EVDD - 0.31V		V
		Pin Group 2D	Center point at 0.6·EVDD Note3		0.192·EVDD - 0.31V		V
	VHYS5	Pin Group 6	Center point at 0.5·EVDD Note3		0.535·EVDD - 0.9V		V
High level output voltage Note2	VOH1	Pin Group 1x, 2x	IOH=-1.0mA	EVDD-1.0		EVDD	V
			IOH=-100μA	EVDD-0.5		EVDD	V
	VOH3	Pin Group 4	IOH=-1.0mA	AVREF0-1.0		AVREF0	V
			IOH=-100μA	AVREF0-0.5		AVREF0	V
Low level output voltage Note2	VOL1	Pin Group 1x, 2x	IOL=1.0mA	0		0.4	V
		P914, 915	IOL=3.0mA				
	VOL3	Pin Group 4	IOL=1.0mA	0		0.4	V
Software pull-up resistor	R1	VI=0V		10	30	100	kΩ
Software Note1 pull-down resistor	R2	VI=VDD		10	30	100	kΩ

Remark: The characteristics of the dual-function pins are the same as those of the port pins unless otherwise specified.

Notes: 1. $\overline{\text{DRST}}$ terminal only. (Control register is OCDM)

2. Total IOH/IOL for each power supply line (EVDD and AVREF0).
- (A-Grade) :max 20mA/-20mA
- (A1-/A2-Grade): max. 10mA/-10mA

AVREF0 IOH/IOL current is excluding ADC0 current IAREF0.

3. Typical value. Not tested and guaranteed

2.6.2 PIN leakage current

(C=4.7uF, VDD = EVDD = 3.3 to 5.5V, AVREF0 = 3.3 to 5.5V, VSS = EVSS = AVSS = 0V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.			Unit
						(A)	(A1)	(A2)	
High level input leakage current	ILIH1	VI=VDD	Analog pins			0.2	0.4	0.5	µA
			Other pins Note1			0.5	0.8	1.0	
Low level input leakage current	ILIL1	VI=0V	Analog pins			-0.2	-0.4	-0.5	
			Other pins Note1			-0.5	-0.8	-1.0	
High level output leakage current	ILOH1	VO=VDD	Analog pins			0.2	0.4	0.5	
			Other pins			0.5	0.8	1.0	
Low level output leakage current	ILOL1	VO=0V	Analog pins			-0.2	-0.4	-0.5	
			Other pins			-0.5	-0.8	-1.0	

Notes: 1. The input leakage current of FLMD0 is as follows:
High level input leakage current :
- (A)-Grade 2.0µA
- (A1)-Grade 4.0µA
- (A2)-Grade 5.0µA

Low level input leakage current:
- (A)-Grade -2.0µA
- (A1)-Grade -4.0µA
- (A2)-Grade 5.0µA

2.6.3 Power supply current

2.6.3.1 FF3-L µPD70F3615, µPD70F3616, µPD70F3617, µPD70F3618, µPD70F3619

(a) Absolute values

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, C=4.7uF, VDD = EVDD = 3.3 to 5.5V, AVREF0 = 3.3 to 5.5V, VSS = EVSS = AVSS = 0V[Note1])

Mode	Symbol	Condition				TYP.	MAX.			Unit
							(A)	(A1)	(A2)	
Operating mode Note2	IDD1	All peripherals running	Peripheral: f_{xx} PRSI option: 0	PLL: ON 16MHz≤f_{xx}≤20MHz	f_{xx}=10MHz f_x=5MHz	16	24			mA
					f_{xx}=20MHz f_x=10MHz	25	35			mA
				PLL: OFF 4MHz≤f_{xx}≤16MHz	f_{xx}=8MHz 8MHz Internal-OSC Note3	12	19			mA
					f_{xx}=16MHz f_x=16MHz	20	28			mA
			Peripheral: f_{xx}/2 PRSI option: 1	PLL: ON 10MHz≤f_{xx}≤20MHz	f_{xx}=20MHz f_x=10MHz	22	32			mA
		All peripherals stopped	Peripheral: f_{xx} PRSI option: 0	PLL: ON 16MHz≤f_{xx}≤20MHz	f_{xx}=10MHz f_x=5MHz	13	-			mA
					f_{xx}=20MHz f_x=10MHz	21				mA
				PLL: OFF 4MHz≤f_{xx}≤16MHz	f_{xx}=8MHz 8MHz Internal-OSC Note3	11				mA
					f_{xx}=16MHz f_x=16MHz	18				mA
			Peripheral: f_{xx}/2 PRSI option: 1	PLL: ON 10MHz≤f_{xx}≤20MHz	f_{xx}=20MHz f_x=10MHz	21				mA

Mode	Symbol	Condition				TYP.	MAX.			Unit
							(A)	(A1)	(A2)	
HALT mode	IDD2	All peripherals running	Peripheral: f_{xx} PRSI option: 0	PLL: ON 16MHz≤f_{xx}≤20MHz	f_{xx}=10MHz f_x=5MHz	10	15			mA
					f_{xx}=20MHz f_x=10MHz	17	25			mA
				PLL: OFF 4MHz≤f_{xx}≤16MHz	f_{xx}=8MHz 8MHz Internal-OSC Note3	7	11			mA
					f_{xx}=16MHz f_x=16MHz	12	18			mA
			Peripheral: f_{xx}/2 PRSI option: 1	PLL: ON 10MHz≤f_{xx}≤20MHz	f_{xx}=20MHz f_x=10MHz	14	21			mA
		All peripherals stopped	Peripheral: f_{xx} PRSI option: 0	PLL: ON 16MHz≤f_{xx}≤20MHz	f_{xx}=10MHz f_x=5MHz	7	-			mA
					f_{xx}=20MHz f_x=10MHz	12				mA
				PLL: OFF 4MHz≤f_{xx}≤16MHz	f_{xx}=8MHz 8MHz Internal-OSC Note3	5				mA
					f_{xx}=16MHz f_x=16MHz	9				mA
			Peripheral: f_{xx}/2 PRSI option: 1	PLL: ON 10MHz≤f_{xx}≤20MHz	f_{xx}=20MHz f_x=10MHz	11				mA

Notes: 1. VDD and EVDD total current. (Ports are stopped).
AVREF0 current, port buffer current (including a current flowing in the on-chip pull-up/pull-down resistor) are not included.

2. The code flash is in read mode.
When the device is in programming mode (Self-programming mode) the current value (MAX. value) adds by the following value:

- Self-programming mode:
  + In case of PLL OFF: 7-(0.33*fxx+0.1) [mA]
  + In case of PLL ON: 7-(0.18*fxx+3.0) [mA]

3. Main OSC is stopped.

4. Do not use SubOSC.

5. POC is working. 240kHz Internal-OSC is working. 8MHz Internal-OSC is stopped.

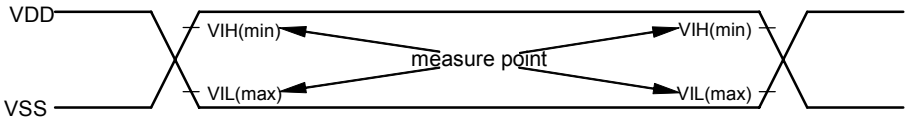
6. RC Oscillation frequency is typ.40kHz. This clock is divided by 1/2 internally.

7. 8MHz Internal-OSC is stopped

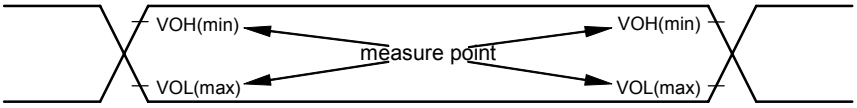
8. The formulas are for reference only. Not all possible values for f_{xx} are tested in the outgoing device inspection.

2.7 AC Characteristics

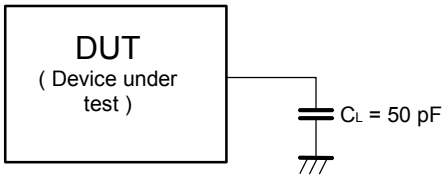
AC test Input measurement points (VDD, AVREF0, EVDD)



AC test output measurement points



Load conditions



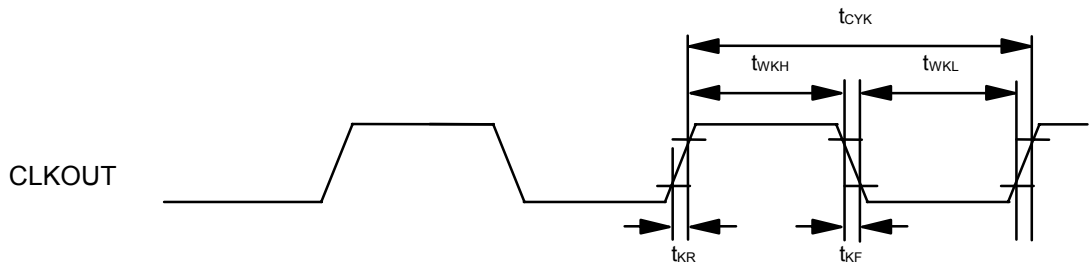
Caution: If the load capacitance exceeds 50pF due to the circuit configuration, reduce the load capacitance of the device to 50pF or less by inserting a buffer or by some other means.

2.7.1 CLKOUT Output Timing

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, VDD = EVDD = 3.5 to 5.5V, AVREF0 = 3.5 to 5.5V, VSS = EVSS = AVSS = 0V, CL=50pF)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Output cycle	tCYK		50ns	80μs	
High level width	tWKH	VDD = EVDD = 4.0V ~ 5.5V	tCYK/2-13		ns
		VDD = EVDD = 3.5V ~ 5.5V	tCYK/2-15		
Low level width	tWKL	VDD = EVDD = 4.0V ~ 5.5V	tCYK/2-13		ns
		VDD = EVDD = 3.5V ~ 5.5V	tCYK/2-15		
Rise time	tKR	VDD = EVDD = 4.0V ~ 5.5V		13	ns
		VDD = EVDD = 3.5V ~ 5.5V		15	
Fall time	tKF	VDD = EVDD = 4.0V ~ 5.5V		13	ns
		VDD = EVDD = 3.5V ~ 5.5V		15	

CLKOUT output timing



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2.7.7 IIC Timing

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, VDD = EVDD = 3.5 to 5.5V, AVREF0 = 3.5 to 5.5V, VSS = EVSS = AVSS = 0V, CL=50pF)

Parameter		Symbol	Normal mode		High-speed mode		Unit
			min.	max.	min.	max.	
SCL00 clock frequency		fCLK	0	100	0	400	kHz
Bus-free time (between stop/start conditions)		tBUF	4.7		1.3		µs
Hold time[Note1]		tHD:STA	4.0		0.6		µs
SCL00 clock low-level width		tLOW	4.7		1.3		µs
SCL00 clock high-level width		tHIGH	4.0		0.6		µs
Setup time for start/restart conditions		tSU:STA	4.7		0.6		µs
Data hold time	CBUS compatible master	tHD:DAT	5.0				µs
	IIC mode		0[Note2]		0[Note2]	0.9[Note3]	µs
Data setup time		tSU:DAT	250		100[Note4]		ns
SDA00 and SCL00 signal rise time		tR		1000	20+0.1Cb	300	ns
SDA00 and SCL00 signal fall time		tF		300	20+0.1Cb	300	ns
Stop condition setup time		tSU:STO	4.0		0.6		µs
Pilse width with spike supporessed by input filter		tSP			0	50	ns
Capacitance load of each bus line		Cb		400		400	pF

Notes: 1. At the start condition, the first clock pulse is generated after the hold time

2. The system requires a minimum of 300ns hold time Internally for the SDA signal (at VIH-min. of SCL00 signal)
In order to occupy the undefined area at the falling edge of SCL00.

3. If the system does not extend the SCL00 signal low hold time (tlow), only the maximum data hold time (tHD:DAT) needs to be satisfied.

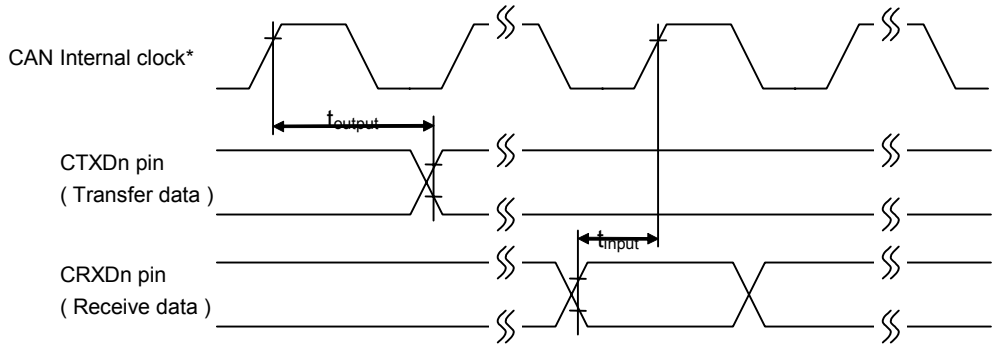
4. The high-speed-mode IIC bus can be used In a normal-mode IIC bus system.
In this case, set the high-speed-mode IIC bus so that It meets the following conditions.
- If the system does not extend the SCL00 signal's low state hold time:
SU:DAT?250ns
- If the system extends the SCL00 signal's low state hold time:
Transmit the following data bit to the SDA00 line prior to releasing the SCL00 line (tRmax.+tSU:DAT=1000+250=1250ns: Normal mode IIC bus specification).

5. Cb: Total capacitance of one bus line (unit: pF)

2.7.8 CAN Timing

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, VDD = EVDD = 3.5 to 5.5V, AVREF0 = 3.5 to 5.5V, VSS = EVSS = AVSS = 0V, CL=50pF)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate					1	Mbps
Internal delay time					100	ns



Internal delay time (tNODE)= Internal Transfer Delay(t_{output}) + Internal Receive Delay(t_{input})

*) CAN Internal clock (f_{CAN}) :CAN baud rate clock

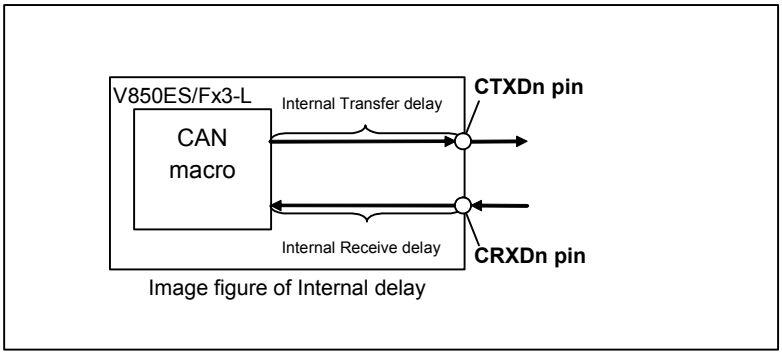


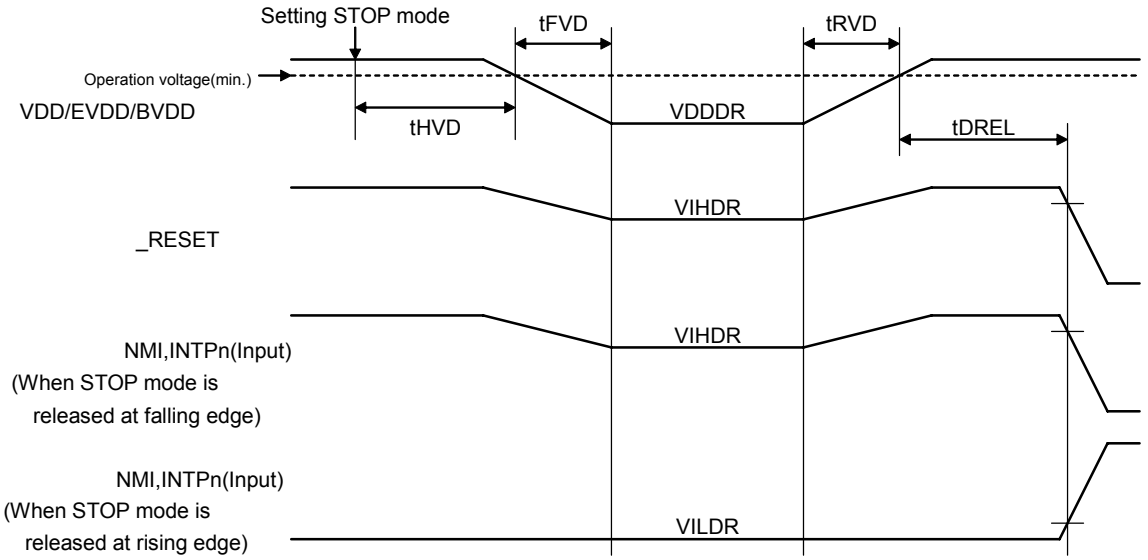
Image figure of Internal delay

2.12 Data Retention Characteristics

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, C=4.7uF, VDD = EVDD = 1.9 to 5.5V, VSS = EVSS = AVSS = 0V) (

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention power supply voltage	VDDDR	STOP mode (All function is stopped)	1.9		5.5	V
Data retention power supply current	IDDDR	VDDDR=2.0V(All function is stopped)		6.5	70	μA
Supply voltage rise time	tRVD		1			μs
Supply voltage fall time	tFVD		1			μs
Supply voltage hold time	tHVD	After STOP mode	0			ms
STOP release signal input time	tDREL	After VDD reaches operating voltage range MIN. 3.3V	0			ms
Data retention high-level input voltage	VIHDR	All input port	0.9·VDDDR		VDDDR	V
Data retention low-level input voltage	VILDR	All input port	0		0.1·VDDDR	V

Remark: When STOP mode is entered/released operation voltage range must be controlled.



2.13 Flash Memory Programming Characteristics

(a) Basic Characteristics

(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, C=4.7uF, VDD = EVDD, AVREF0 = 3.5 to 5.5V, VSS = EVSS = AVSS = 0V)

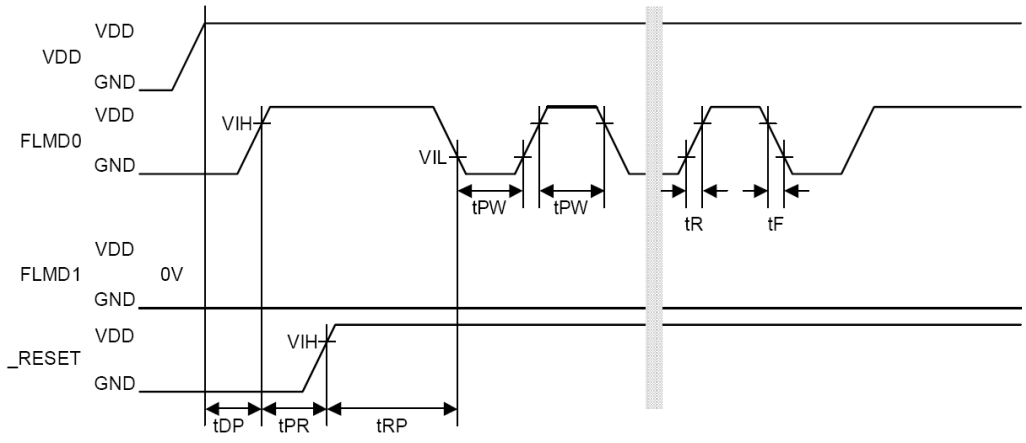
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.			Unit
					(A)	(A1)	(A2)	
Operation frequency	fCPU		4		20			MHz
Supply voltage	VDD		3.3		5.5			V
Number of rewrites	CWRT	Code Flash			1000			count
High level input voltage	VIH	FLMD0	0.8·EVDD		EVDD			V
Low level input voltage	VIL	FLMD0	EVSS		0.2·EVDD			V
Programming temperature	tPRG		-40		+85	+110	+125	°C
Data retention		Code Flash	15					year

Remark: The initial write when the product is shipped, any erase → write set of operations, or any programming operation is counted as one rewrite.
Example: P: Program(write) E: Erase
Product is shipped → P → E → P → E → P : Rewrite count: 3
Product is shipped → E → P → E → P → E → P : Rewrite count: 3

(b) Serial Writing Operation Characteristics

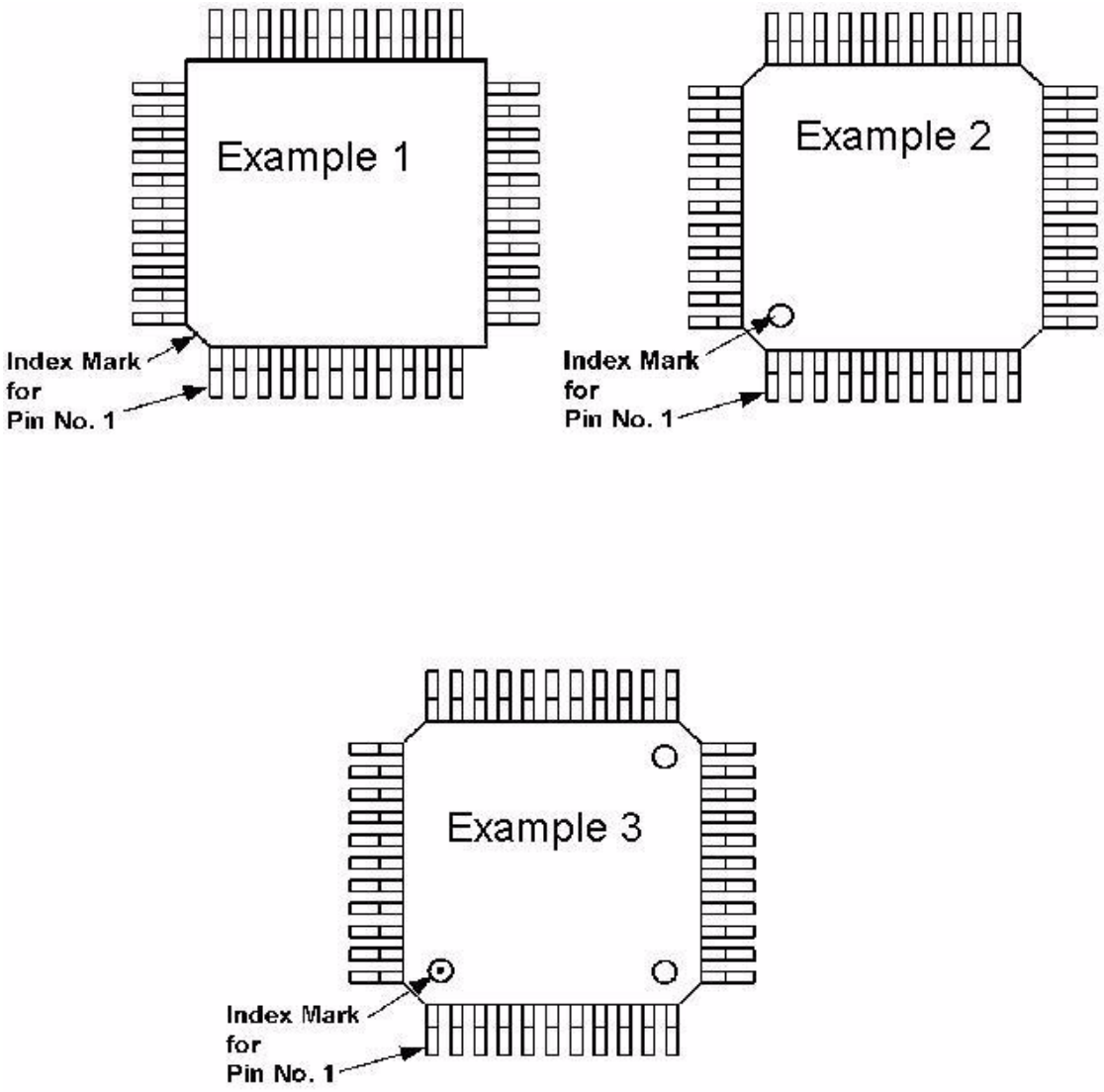
(Ta = -40 to +85°C for (A)-Grade, Ta = -40 to +110°C for (A1)-Grade, Ta = -40 to +125°C for (A2)-Grade, C=4.7uF, VDD = EVDD, AVREF0 = 3.5 to 5.5V, VSS = EVSS = AVSS = 0V, CL=50pF)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
FLMD0 setup time (from VDD)	tDP		1			ms
$\overline{\text{RESET}}$ release (from FLMD0)	tPR		2			ms
FLMD0 pulse input start (from raise edge of _RESET)	tRP		800			µs
FLMD0 high level width / low level width	tPW		10		100	µs
FLMD0 raise time	tR				50	ns
FLMD0 fall time	tF				50	ns



3.2 Product Marking

3.2.1 Marking of pin 1 at a QFP (Quad Flat Package)



Example 1: The index mark for pin 1 is the beveled edge of the package

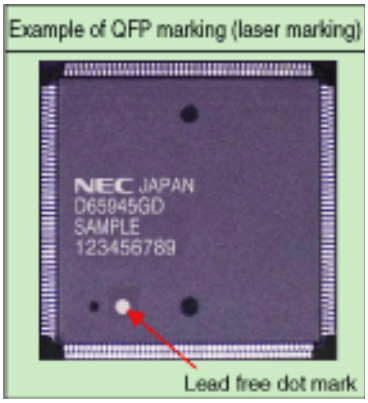
Example 2: The index mark for pin 1 is a round notch at one of the 4 edges. In this case, the shape of all edges is identical (usually beveled).

Example 3: For production reasons, two or more similar notches may be located at the top of the package. In such a case the index marker for pin 1 is a round notch with an additional mark in it.

Note: RoHS compliant devices have an additional dot at the top side. Do not mix it up with the marking for pin 1. For details see 3.2.2 "Identification of Lead-Free Products" on page 34.

3.2.2 Identification of Lead-Free Products

Lead-Free products are marked with a dot "•". The marking methods are the paint or the laser (It doesn't sink in). The shape of lead-free marks is a circle.
Example:



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